AMENDMENTS TO THE CLAIMS

- 1. (Canceled).
- 2. (Currently Amended) The monolithic multi-focal length refractive element as recited in Claim 5 [[1]], wherein a the value of an optical property for said first surface region is different from a value of said optical property for said second surface region.
- 3. (Original) The monolithic multi-focal length refractive element as recited in Claim 2 wherein said optical element blank comprises silica (SiO₂).
- 4. (Original) The monolithic multi-focal length refractive element as recited in Claim 2 wherein said optical element blank comprises gallium arsenide (GaAs).
- 5. (Currently Amended) The monolithic multi-focal length refractive element as recited in Claim 1 A monolithic multi-focal length refractive element comprising:

a single monolithic optical element blank comprising:

a first surface region having a first characteristic radius of curvature; and

a second surface region having a second characteristic radius of curvature, wherein said monolithic multi-focal length refractive element has a maximum dimension of less than five millimeters.

6. (Currently Amended) The monolithic multi-focal length refractive element as recited in Claim 5 [[1]], wherein said monolithic

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optical element blank comprises a third surface region having a third characteristic radius of curvature.

7-8. (Canceled).

9. (Currently Amended) The method as recited in Claim 8 A method for making a multi-focal length refractive element, said method comprising:

forming in an optical element blank a first surface region

characterized by a first radius of curvature by etching said optical element

blank using a first etch process having a first etch selectivity; and

forming on said optical element blank a second surface region

characterized by a second radius of curvature by wherein said forming said

second surface region comprises etching said optical element blank using a

second etch process having a second etch selectivity.

- 10. (Original) The method as recited in Claim 9 wherein said first etch selectivity is less than said second etch selectivity.
- 11. (Currently Amended) The method as recited in Claim 9 [[7]] additionally comprising forming a first shape transfer mask and etching said first shape transfer mask using said a first etch process.
- 12. (Currently Amended) The method as recited in Claim 11 additionally comprising etching said first shape transfer mask using said a second etch process.
- 13. (Currently Amended) The method as recited in Claim 11 [[13]] additionally comprising forming a second shape transfer mask.

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14. (Currently Amended) The method as recited in Claim 13 additionally comprising using said a second etch process to etch said second shape transfer mask.

15-23. (Canceled).

24. (New) A method for making a multi-focal length refractive element, said method comprising:

forming in an optical element blank a first surface region characterized by a first radius of curvature;

forming on said optical element blank a second surface region characterized by a second radius of curvature;

forming a first shape transfer mask and etching said first shape transfer mask using a first etch process; and

etching said first shape transfer mask using a second etch process.

- 25. (New) The method as recited in Claim 24 wherein said forming said first surface region comprises etching said optical element blank using said first etch process having a first etch selectivity.
- 26. (New) The method as recited in Claim 25 wherein said forming said second surface region comprises etching said optical element blank using said second etch process having a second etch selectivity.
- 27. (New) The method as recited in Claim 26 wherein said first etch selectivity is less than said second etch selectivity.

10020858-1 Examiner: CHOI, W. 28. (New) The method as recited in Claim 24 additionally comprising forming a second shape transfer mask.

29. (New) The method as recited in Claim 28 additionally comprising using said second etch process to etch said second shape transfer mask.

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